

2-input OR Gate

REJ03D0203-0500Z (Previous ADE-205-018C (Z)) Rev.5.00 Feb.02.2004

Description

The HD74UH32 is high speed CMOS two input OR gate using silicon gate CMOS process. With CMOS low power dissipation, it provides high-speed equivalent to LS-TTL series. The internal circuit of three stages construction with buffer provides wide noise margin and stable output.

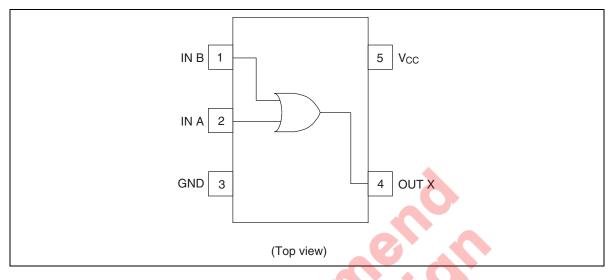
Features

- Encapsulated in very small 5pins package of $2.9 \times 1.6 \times 1.1$ mm, the efficiency to mount on substrate is significantly improved.
- The basic gate function is lined up as Renesas uni logic series.
- Supplied on emboss taping for high-speed automatic mounting.
- Electrical characteristics equivalent to the HD74HC32 Supply voltage range: 2 to 6 V Operating temperature range: -40 to +85°C
- $|I_{OH}| = I_{OL} = 2 \text{ mA (min)}$
- Ordering Information

HD74UH32EL MPAK-5 pin MPAK-5V – EL (3,000 pcs/reel)	Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
	HD74UH32EL	MPAK-5 pin	MPAK-5V	_	EL (3,000 pcs/reel)



Pin Arrangement



Article Indication

Marking Lot number
H 4 A

Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Supply voltage	V _{CC}	-0.5 to +7.0	V
Input voltage	V _{IN}	–0.5 to V _{CC} +0.5	V
Output voltage	V _{OUT}	-0.5 to V _{CC} +0.5	V
Input diode current	l _{IK}	±20	mA
Output diode current	Ι _{ΟK}	±20	mA
Output current	I _{OUT}	±25	mA
V _{CC} /GND current	I _{CC} , I _{GND}	±25	mA
Power dissipation	P _T	200	mW
Storage temperature	Tstg	–65 to +150	°C

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Recommended Operating Conditions

Item	Symbol	Ratings	Unit	
Supply voltage	V _{CC}	2 to 6	V	
Input voltage	VIN	0 to V _{CC}	V	
Output voltage	V _{OUT}	0 to V _{CC}	V	
Operating temperature	Topr	-40 to +85	°C	
Input rise/fall time	t _r , t _f	0 to 1000 (V _{CC} = 2.0 V)	ns	
		0 to 500 ($V_{CC} = 4.5 V$)		
		0 to 400 ($V_{CC} = 6.0 V$)		

Electrical Characteristics

Electrical Characteristics										
		Vcc	Ta =	25°C		Ta =	–40 to 85°C		\mathbf{O}	
Item	Symbol	(V)	Min	Тур	Max	Min	Max	Unit	Test Con	ditions
Input voltage	VIH	2.0	1.5			1.5	-	V	2	
		4.5	3.15		—	3.15	V - C			
		6.0	4.2	—		4.2	10			
	VIL	2.0	_	_	0.5) <u> </u>	0.5	V		
		4.5	_	F	1.35	_	1.35	_		
		6.0	-0	7	1.8	-	1.8	_		
Output voltage	V _{OH}	2.0	1.9	2.0		1.9		V		I _{OH} = -20 μA
		4.5	4.4	4.5	4	4.4	—			
		6.0	5.9	6.0		5.9	—	_		
		4.5	4.18	4.31	_	4.13	—	_		$I_{OH} = -2 \text{ mA}$
		6.0	5.68	5.80	_	5.63	_	_		I _{OH} = -2.6 mA
	Vol	2.0		0.0	0.1	_	0.1	V	$V_{\text{IN}} = V_{\text{IL}}$	I _{OL} = 20 μA
	-	4.5	_	0.0	0.1	_	0.1	_		
		6.0	_	0.0	0.1	_	0.1	_		
		4.5		0.17	0.26	—	0.33	_		$I_{OL} = 2 \text{ mA}$
		6.0	—	0.18	0.26	—	0.33	-		I _{OL} = 2.6 mA
Input current	I _{IN}	6.0	—	—	±0.1	—	±1.0	μA	$V_{IN} = V_{CC}$	or GND
Operating current	Icc	6.0	—	—	1.0	—	10.0	_	$V_{IN} = V_{CC}$	or GND



Switching Characteristics

 $(C_L = 15 \text{ pF}, t_r = t_f = 6 \text{ ns}, V_{CC} = 5 \text{ V})$

Ta = 25°C						
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Output rise/fall time	t _{TLH} t _{THL}	—	5	10	ns	See Test circuit
Propagation delay time	t _{PLH} t _{PHL}	_	7	15	ns	See Test circuit

 $(C_L = 50 \text{ pF}, t_r = t_f = 6 \text{ ns})$

		\textbf{V}_{CC}	Ta = 25°C		Ta = -40 to 85°C				
ltem	Symbol	(V)	Min	Тур	Max	Min	Max	Unit	Test Conditions
Output rise/fall time	t_{TLH}	2.0	_	50	125	-	155	ns	See Test circuit
	t⊤⊣∟	4.5	_	14	25		31		
		6.0	_	12	21		26		
Propagation delay time	t _{PLH}	2.0	—	48	100	-	125	ns	See Test circuit
	t _{PHL}	4.5	—	12	20	-0	25	-	
		6.0	-	9	17		21	-	
Input capacitance	C _{IN}	-	5	5	10	-	10	pF	
Equivalent capacitance	CPD	4		10		_	_	-	

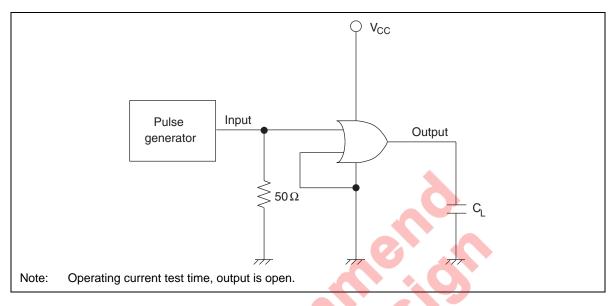
Note: C_{PD} is equivalent capacitance inside of the IC calculated from the operating current without load (see test circuit). The average operating current without load is calculated according to the expression below.

 $I_{CC(opr)} = C_{PD} \bullet V_{CC} \bullet f_{IN} + I_{CC}$

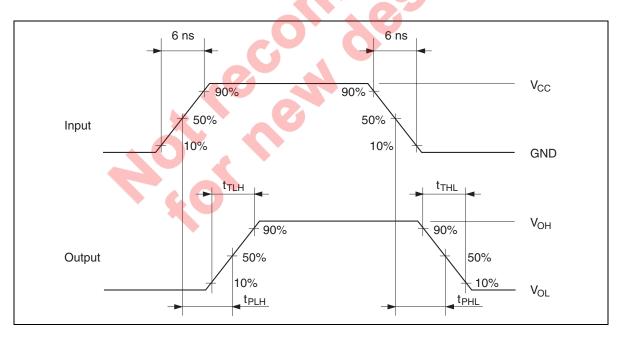
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Test Circuit

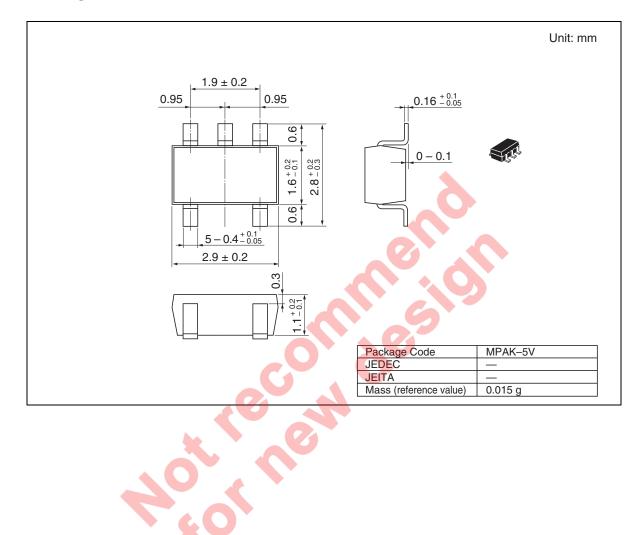


Waveforms





Package Dimensions



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